NSN 5962-01-099-6383

Memory Microcircuit - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5962-01-099-6383 **Body Length:** Between 0.882 inches and 0.925 inches **Body Width:** 0.310 inches **Body Height:** Between 0.145 inches and 0.175 inches **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Hermetically sealed and monolithic and positive outputs and w/enable and w/open collector and 3-state output **Inclosure Material:** Ceramic and glass **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 12 input **Terminal Surface Treatment:** Solder **Voltage Rating And Type Per Characteristic:** 5.5 volts power source **Time Rating Per Chacteristic:** 40.00 nanoseconds propagation delay time, low to high level output and 40.00 nanoseconds propagation delay time, high to low level output **Memory Device Type:** Rom **Test Data Document:** 11627-21008 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 18 printed circuit Shelf Life: N/a **Unit Of Measure:**

Yes - demil/mli

Demilitarization:

Fiig:

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